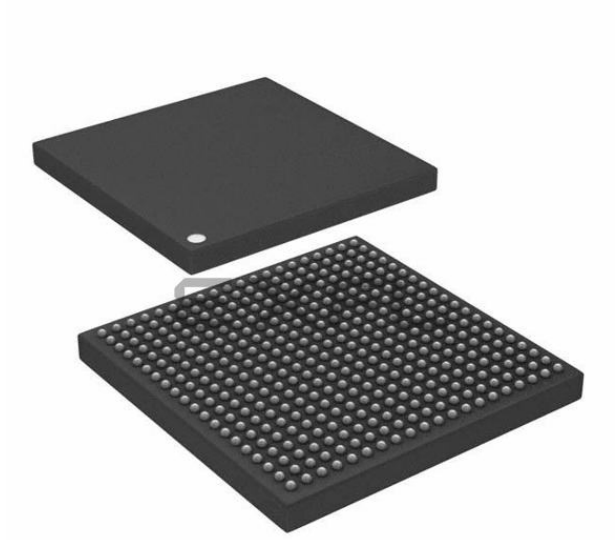

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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	ARM1136JF-S
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	532MHz
Co-Processors/DSP	Multimedia; GPU, IPU, VFP
RAM Controllers	LPDDR, DDR2
Graphics Acceleration	Yes
Display & Interface Controllers	Keypad, KPP, LCD
Ethernet	10/100Mbps (1)
SATA	-
USB	USB 2.0 + PHY (2)
Voltage - I/O	1.8V, 2.0V, 2.5V, 2.7V, 3.0V, 3.3V
Operating Temperature	-40°C ~ 85°C (TA)
Security Features	Secure Fusebox, Secure JTAG, Tamper Detection
Package / Case	400-LFBGA
Supplier Device Package	400-LFBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx353cjq5cr2

The i.MX35 core is intended to operate at a maximum frequency of 532 MHz to support the required multimedia use cases. Furthermore, an image processing unit (IPU) is integrated into the AP domain to offload the ARM11 core from performing functions such as color space conversion, image rotation and scaling, graphics overlay, and pre- and post-processing.

The functionality of AP Domain peripherals includes the user interface; the connectivity, display, security, and memory interfaces; and 128 Kbytes of multipurpose SRAM.

2.2 Shared Domain Overview

The shared domain is composed of the shared peripherals, a smart DMA engine (SDMA) and a number of miscellaneous modules. For maximum flexibility, some peripherals are directly accessible by the SDMA engine.

The i.MX35 has a hierarchical memory architecture including L1 caches and a unified L2 cache. This reduces the bandwidth demands for the external bus and external memory. The external memory subsystem supports a flexible external memory system, including support for SDRAM (SDR, DDR2 and mobile DDR) and NAND Flash.

2.3 Advanced Power Management Overview

To address the continuing need to reduce power consumption, the following techniques are incorporated in the i.MX35:

- Clock gating
- Power gating
- Power-optimized synthesis
- Well biasing

The insertion of gating into the clock paths allows unused portions of the chip to be disabled. Because static CMOS logic consumes only leakage power, significant power savings can be realized.

"Well biasing" is applying a voltage that is greater than V_{DD} to the nwells, and one that is lower than V_{SS} to the pwells. The effect of applying this well back bias voltage reduces the subthreshold channel leakage. For the 90-nm digital process, it is estimated that the subthreshold leakage is reduced by a factor of ten over the nominal leakage. Additionally, the supply voltage for internal logic can be reduced from 1.4 V to 1.22 V.

2.4 ARM11 Microprocessor Core

The CPU of the i.MX35 is the ARM1136JF-S core, based on the ARM v6 architecture. This core supports the ARM Thumb® instruction sets, features Jazelle® technology (which enables direct execution of Java byte codes) and a range of SIMD DSP instructions that operate on 16-bit or 8-bit data values in 32-bit registers.

The ARM1136JF-S processor core features are as follows:

- Integer unit with integral EmbeddedICE™ logic
- Eight-stage pipeline

- Branch prediction with return stack
- Low-interrupt latency
- Instruction and data memory management units (MMUs), managed using micro TLB structures backed by a unified main TLB
- Instruction and data L1 caches, including a non-blocking data cache with hit-under-miss
- Virtually indexed/physically addressed L1 caches
- 64-bit interface to both L1 caches
- Write buffer (bypassable)
- High-speed Advanced Micro Bus Architecture (AMBA)™ L2 interface
- Vector floating point co-processor (VFP) for 3D graphics and hardware acceleration of other floating-point applications
- ETM™ and JTAG-based debug support

Table 3 summarizes information about the i.MX35 core.

Table 3. i.MX35 Core

Core Acronym	Core Name	Brief Description	Integrated Memory Features
ARM11 or ARM1136	ARM1136 Platform	The ARM1136™ platform consists of the ARM1136JF-S core, the ETM real-time debug modules, a 6 × 5 multi-layer AHB crossbar switch (MAX), and a vector floating processor (VFP). The i.MX35 provides a high-performance ARM11 microprocessor core and highly integrated system functions. The ARM Application Processor (AP) and other subsystems address the needs of the personal, wireless, and portable product market with integrated peripherals, advanced processor core, and power management capabilities.	• 16-Kbyte instruction cache • 16-Kbyte data cache • 128-Kbyte L2 cache • 32-Kbyte ROM • 128-Kbyte RAM

2.5 Module Inventory

Table 4 shows an alphabetical listing of the modules in the MCIMX35. For extended descriptions of the modules, see the MCIMX35 reference manual.

Table 4. Digital and Analog Modules

Block Mnemonic	Block Name	Domain[1]	Subsystem	Brief Description
1-WIRE	1-Wire interface	ARM	ARM1136 platform peripherals	1-Wire provides the communication line to a 1-Kbit add-only memory. the interface can send or receive 1 bit at a time.
ASRC	Asynchronous sample rate converter	SDMA	Connectivity peripherals	The ASRC is designed to convert the sampling rate of a signal associated to an input clock into a signal associated to a different output clock. It supports a concurrent sample rate conversion of about –120 dB THD+N. The sample rate conversion of each channel is associated to a pair of incoming and outgoing sampling rates.

Table 4. Digital and Analog Modules (continued)

Block Mnemonic	Block Name	Domain[1]	Subsystem	Brief Description
MPLL PPLL	Digital phase-locked loops	SDMA	Clocks	DPLLs are used to generate the clocks: MCU PLL (MPLL)—programmable Peripheral PLL (PPLL)—programmable
PWM	Pulse-width modulator	ARM	ARM1136 platform peripherals	The pulse-width modulator (PWM) is optimized to generate sound from stored sample audio images; it can also generate tones.
RTC	Real-time clock	ARM	Clocks	Provides the ARM1136 platform with a clock function (days, hours, minutes, seconds) and includes alarm, sampling timer, and minute stopwatch capabilities.
SDMA	Smart DMA engine	SDMA	System controls	The SDMA provides DMA capabilities inside the processor. It is a shared module that implements 32 DMA channels and has an interface to connect to the ARM1136 platform subsystem, EMI interface, and the peripherals.
SJC	Secure JTAG controller	ARM	Pins	The secure JTAG controller (SJC) provides debug and test control with maximum security.
SPBA	SDMA peripheral bus arbiter	SDMA	System controls	The SPBA controls access to the SDMA peripherals. It supports shared peripheral ownership and access rights to an owned peripheral.
S/PDIF	Serial audio interface	SDMA	Connectivity peripherals	Sony/Philips digital transceiver interface
SSI(2)	Synchronous serial interface	SDMA, ARM(2)	Connectivity peripherals	The SSI is a full-duplex serial port that allows the processor connected to it to communicate with a variety of serial protocols, including the Freescale Semiconductor SPI standard and the I^2C sound (I^2S) bus standard. The SSIs interface to the AUDMUX for flexible audio routing.
UART(3)	Universal asynchronous receiver/transmitters	ARM (UART1,2) SDMA (UART3)	Connectivity peripherals	Each UART provides serial communication capability with external devices through an RS-232 cable using the standard RS-232 non-return-to-zero (NRZ) encoding format. Each module transmits and receives characters containing either 7 or 8 bits (program-selectable). Each UART can also provide low-speed IrDA compatibility through the use of external circuitry that converts infrared signals to electrical signals (for reception) or transforms electrical signals to signals that drive an infrared LED (for transmission).
USBOH	High-speed USB on-the-go	SDMA	Connectivity peripherals	The USB module provides high performance USB on-the-go (OTG) functionality (up to 480 Mbps), compliant with the USB 2.0 specification, the OTG supplement, and the ULPI 1.0 low pin count specification. The module has DMA capabilities handling data transfer between internal buffers and system memory.
WDOG	Watchdog modules	ARM	Timer peripherals	Each module protects against system failures by providing a method of escaping from unexpected events or programming errors. Once activated, the timer must be serviced by software on a periodic basis. If servicing does not take place, the watchdog times out and then either asserts a system reset signal or an interrupt request signal, depending on the software configuration.

Table 14 shows the DC electrical characteristics for GPIO, DDR2, mobile DDR, and SDRAM pins. The term NVCC refers to the power supply voltage that feeds the I/O of the module in question. For example, NVCC for the SD/MMC interface refers to NVCC_SDIO.

Table 14. I/O Pin DC Electrical Characteristics

Pin	DC Electrical Characteristics	Symbol	Test Condition	Min.	Typ.	Max.	Unit
GPIO	High-level output voltage	Voh	Ioh = –1 mA Ioh = specified drive	NVCC – 0.15 0.8 × NVCC	—	—	V
	Low-level output voltage	Vol	Iol = 1 mA Iol = specified drive	—	—	0.15 0.2 × NVCC	V
	High-level output current for slow mode (Voh = 0.8 × NVCC)	Ioh	Standard drive High drive Max. drive	–2.0 –4.0 –8.0	—	—	mA
	High-level output current for fast mode (Voh = 0.8 × NVCC)	Ioh	Standard drive High drive Max. drive	–4.0 –6.0 –8.0	—	—	mA
	Low-level output current for slow mode (Voh = 0.2 × NVCC)	Iol	Standard drive High drive Max. drive	2.0 4.0 8.0	—	—	mA
	Low-level output current for fast mode (Voh = 0.2 × NVCC)	Iol	Standard drive High drive Max. drive	4.0 6.0 8.0	—	—	mA
	High-level DC Input Voltage with 1.8 V, 3.3 V NVCC (for digital cells in input mode)	VIH	—	0.7 × NVCC	—	NVCC	V
	Low-level DC Input Voltage with 1.8 V, 3.3 V NVCC (for digital cells in input mode	VIL	—	–0.3 V	—	0.3 × NVCC	V
	Input Hysteresis	VHYS	OVDD = 3.3 V OVDD = 1.8 V	—	410 330	—	mV
	Schmitt trigger VT+	VT+	—	0.5 × NVCC	—		V
	Schmitt trigger VT–	VT–	—	—	—	0.5 × NVCC	V
	Pull-up resistor (22 kΩ PU)	Rpu	Vi = 0	—	22	—	kΩ
	Pull-up resistor (47 kΩ PU)	Rpu	Vi = 0	—	47	—	kΩ
	Pull-up resistor (100 kΩ PU)	Rpu	Vi = 0	—	100	—	kΩ
	Pull-down resistor (100 kΩ PD)	Rpd	Vi = NVCC	—	100	—	kΩ
	External resistance to pull keeper up when enabled	Rkpu	Ipu > 620 μA @ min Vddio = 3.0 V	—	—	4.8	kΩ
	External resistance to pull keeper down when enabled	Rkpd	Ipu > 510 μA @min Vddio = 3.0 V	—	—	5.9	kΩ

Figure 6 shows the output pin transition time waveform.

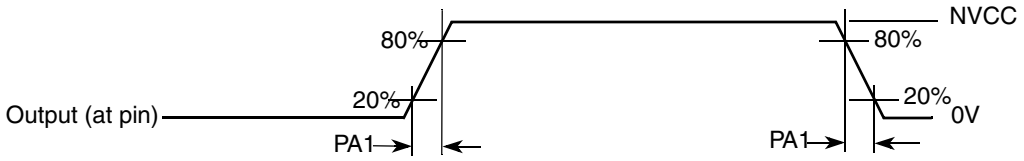


Figure 6. Output Pin Transition Time Waveform

4.8.1 AC Electrical Test Parameter Definitions

AC electrical characteristics in Table 16 through Table 21 are not applicable for the output open drain pull-down driver.

The dI/dt parameters are measured with the following methodology:

- The zero voltage source is connected between pin and load capacitance.
- The current (through this source) derivative is calculated during output transitions.

Table 15. AC Requirements of I/O Pins

Parameter	Symbol	Min.	Max.	Units
AC input logic high	VIH(ac)	NVCC ÷ 2 + 0.25	NVCC + 0.3	V
AC input logic low	VIL(ac)	–0.3	NVCC ÷ 2 – 0.25	V

Table 16. AC Electrical Characteristics of GPIO Pins in Slow Slew Rate Mode [NVCC = 3.0 V–3.6 V]

Parameter	Symbol	Test Condition	Min. Rise/Fall	Typ. Rise/Fall	Max. Rise/Fall	Units
Duty cycle	Fduty	—	40	—	60	%
Output pin slew rate (max. drive)	tps	25 pF 50 pF	0.79/1.12 0.49/0.73	1.30/1.77 0.84/1.23	2.02/2.58 1.19/1.58	V/ns
Output pin slew rate (high drive)	tps	25 pF 50 pF	0.48/0.72 0.27/0.42	0.76/1.10 0.41/0.62	1.17/1.56 0.63/0.86	V/ns
Output pin slew rate (standard drive)	tps	25 pF 50 pF	0.25/0.40 0.14/0.21	0.40/0.59 0.21/0.32	0.60/0.83 0.32/0.44	V/ns
Output pin di/dt (max. drive)	tdit	25 pF 50 pF	15 16	36 38	76 80	mA/ns
Output pin di/dt (high drive)	tdit	25 pF 50 pF	8 9	20 21	45 47	mA/ns
Output pin di/dt (standard drive)	tdit	25 pF 50 pF	4 4	10 10	22 23	mA/ns

Input data, $\overline{\text{ECB}}$ and $\overline{\text{DTACK}}$ all captured according to BCLK rising edge time. Figure 15 depicts the timing of the WEIM module, and Table 33 lists the timing parameters.

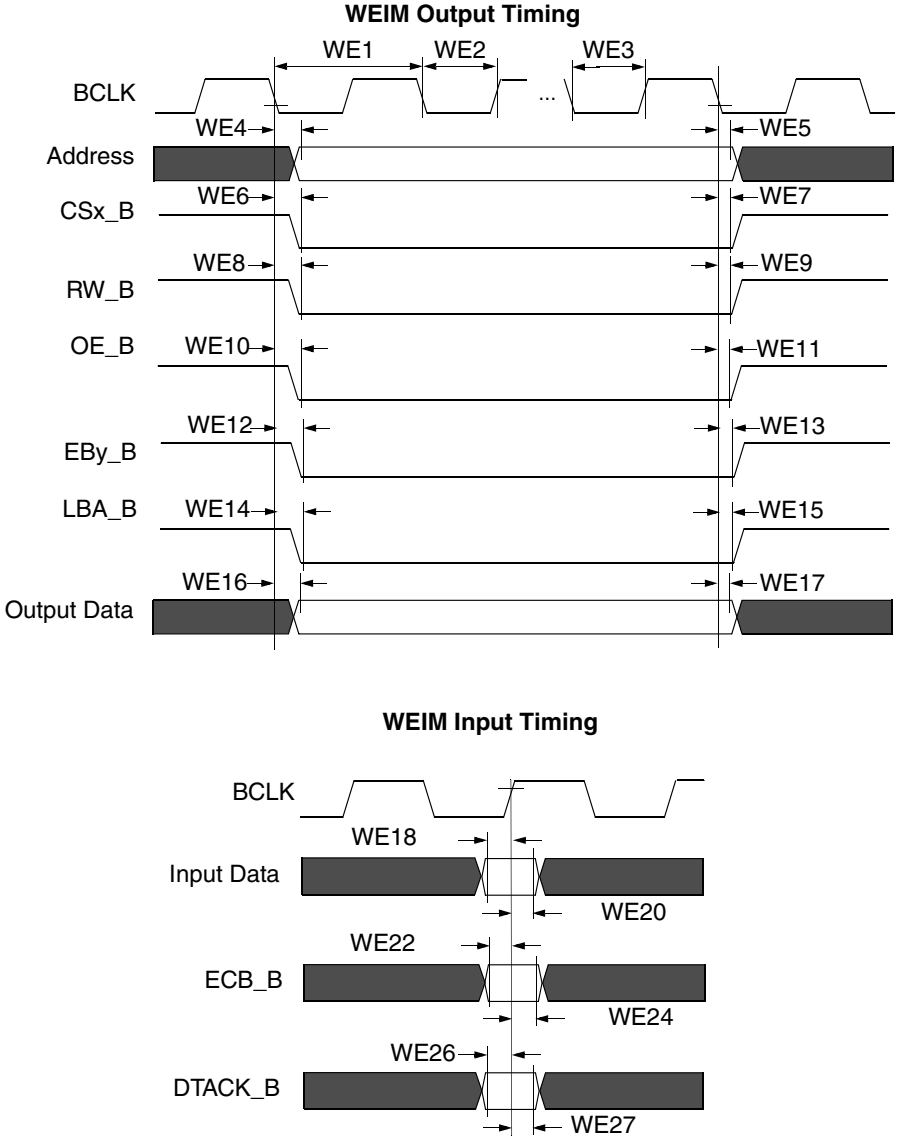


Figure 15. WEIM Bus Timing Diagram

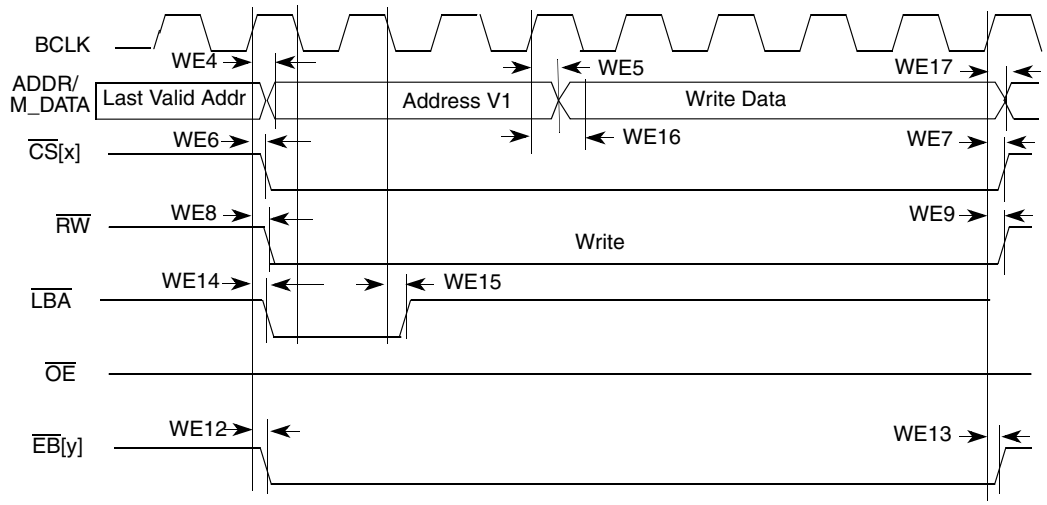


Figure 20. Muxed A/D Mode Timing Diagram for Synchronous Write Access— WSC = 7, LBA = 1, LBN = 1, LAH = 1

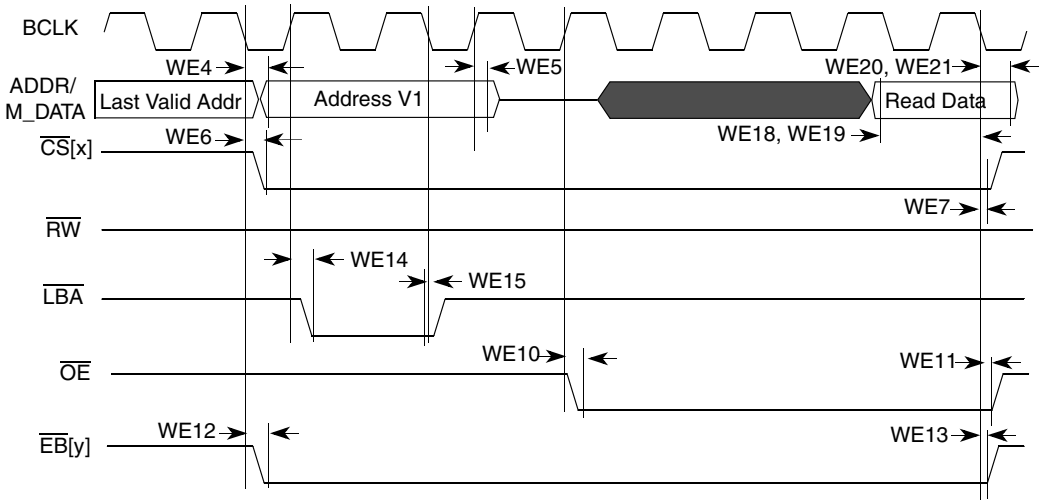


Figure 21. Muxed A/D Mode Timing Diagram for Synchronous Read Access— WSC = 7, LBA = 1, LBN = 1, LAH = 1, OEA = 7

4.9.6 Enhanced Serial Audio Interface (ESAI) Timing Specifications

The ESAI consists of independent transmitter and receiver sections, each section with its own clock generator. Table 46 shows the interface timing values. The number field in the table refers to timing signals found in Figure 36 and Figure 37.

Table 46. Enhanced Serial Audio Interface Timing

No.	Characteristics[1,2]	Symbol	Expression[2]	Min.	Max.	Condition[3]	Unit
62	Clock cycle[4]	t_{SSICC}	$4 \times T_C$ $4 \times T_C$	30.0 30.0	— —	i ck i ck	ns
63	Clock high period • For internal clock • For external clock	— —	$2 \times T_C - 9.0$ $2 \times T_C$	6 15	— —	— —	ns
64	Clock low period • For internal clock • For external clock	— —	$2 \times T_C - 9.0$ $2 \times T_C$	6 15	— —	— —	ns
65	SCKR rising edge to FSR out (bl) high	— —	— —	— —	17.0 7.0	x ck i ck a	ns
66	SCKR rising edge to FSR out (bl) low	— —	— —	— —	17.0 7.0	x ck i ck a	ns
67	SCKR rising edge to FSR out (wr) high[5]	— —	— —	— —	19.0 9.0	x ck i ck a	ns
68	SCKR rising edge to FSR out (wr) low[5]	— —	— —	— —	19.0 9.0	x ck i ck a	ns
69	SCKR rising edge to FSR out (wl) high	— —	— —	— —	16.0 6.0	x ck i ck a	ns
70	SCKR rising edge to FSR out (wl) low	— —	— —	— —	17.0 7.0	x ck i ck a	ns
71	Data in setup time before SCKR (SCK in synchronous mode) falling edge	— —	— —	12.0 19.0	— —	x ck i ck	ns
72	Data in hold time after SCKR falling edge	— —	— —	3.5 9.0	— —	x ck i ck	ns
73	FSR input (bl, wr) high before SCKR falling edge[5]	— —	— —	2.0 12.0	— —	x ck i ck a	ns
74	FSR input (wl) high before SCKR falling edge	— —	— —	2.0 12.0	— —	x ck i ck a	ns
75	FSR input hold time after SCKR falling edge	— —	— —	2.5 8.5	— —	x ck i ck a	ns
78	SCKT rising edge to FST out (bl) high	— —	— —	— —	18.0 8.0	x ck i ck	ns
79	SCKT rising edge to FST out (bl) low	— —	— —	— —	20.0 10.0	x ck i ck	ns

Figure 41 shows MII asynchronous input timings listed in Table 50.

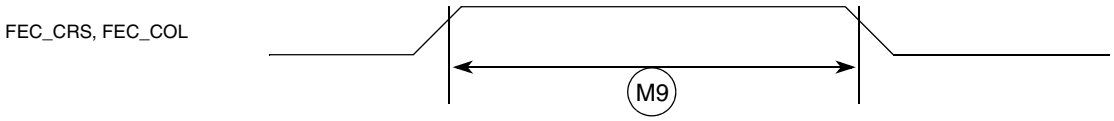


Figure 41. MII Asynch Inputs Timing Diagram

4.9.8.5 MII Serial Management Channel Timing

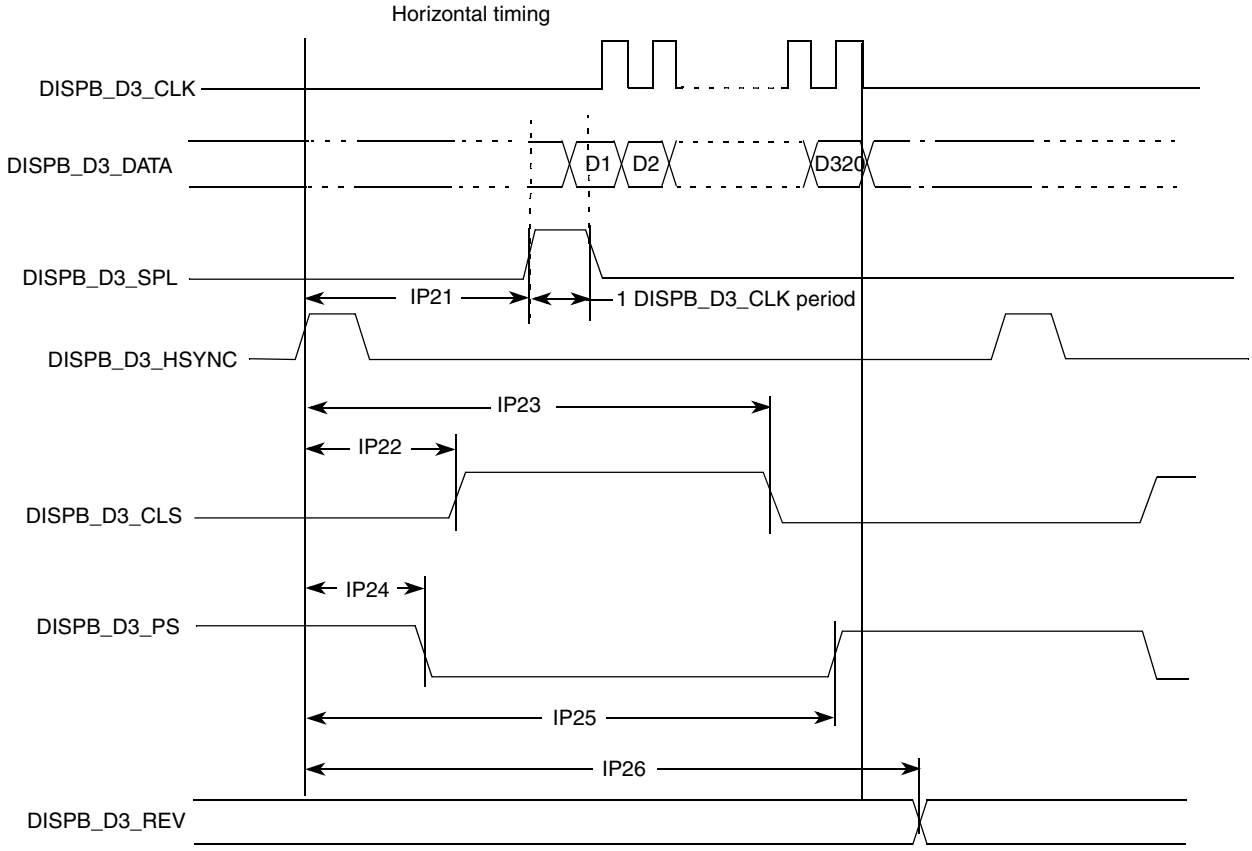
Serial management channel timing is accomplished using FEC_MDIO and FEC_MDC. The FEC functions correctly with a maximum MDC frequency of 2.5 MHz. Table 51 lists MII serial management channel timings.

The MDC frequency should be equal to or less than 2.5 MHz to be compliant with the IEEE 802.3 MII specification. However the FEC can function correctly with a maximum MDC frequency of 15 MHz.

Table 51. MII Transmit Signal Timing

Num	Characteristic	Min.	Max.	Units
M10	FEC_MDC falling edge to FEC_MDIO output invalid (minimum propagation delay)	0	—	ns
M11	FEC_MDC falling edge to FEC_MDIO output valid (max. propagation delay)	—	5	ns
M12	FEC_MDIO (input) to FEC_MDC rising edge setup	18	—	ns
M13	FEC_MDIO (input) to FEC_MDC rising edge hold	0	—	ns
M14	FEC_MDC pulse width high	40%	60%	FEC_MDC period
M15	FEC_MDC pulse width low	40%	60%	FEC_MDC period

Section 4.9.13.1.5, “Interface to Active Matrix TFT LCD Panels, Electrical Characteristics.” The timing images correspond to straight polarity of the Sharp signals.



Example is drawn with FW + 1 = 320 pixel/line, FH + 1 = 240 lines.
SPL pulse width is fixed and aligned to the first data of the line.
REV toggles every HSYNC period.

Figure 51. Sharp HR-TFT Panel Interface Timing Diagram—Pixel Level

Table 57. Sharp Synchronous Display Interface Timing Parameters—Pixel Level

ID	Parameter	Symbol	Value	Units
IP21	SPL rise time	Tsplr	(BGXP – 1) × Tdpcp	ns
IP22	CLS rise time	Tclsr	CLS_RISE_DELAY × Tdpcp	ns
IP23	CLS fall time	Tclsf	CLS_FALL_DELAY × Tdpcp	ns
IP24	CLS rise and PS fall time	Tpsf	PS_FALL_DELAY × Tdpcp	ns
IP25	PS rise time	Tpsr	PS_RISE_DELAY × Tdpcp	ns
IP26	REV toggle time	Trev	REV_TOGGLE_DELAY × Tdpcp	ns

Table 58. Asynchronous Parallel Interface Timing Parameters—Access Level (continued)

ID	Parameter	Symbol	Min.	Typ.[1]	Max.	Units
IP35	Controls setup time for write	Tdcsw	Tdicuw – 1.5	Tdicuw	—	ns
IP36	Controls hold time for write	Tdchw	Tdicpw – Tdicdw – 1.5	Tdicpw – Tdicdw	—	ns
IP37	Slave device data delay[8]	Tracc	0	—	Tdrp[9] – Tlbd[10] – Tdicur – 1.5	ns
IP38	Slave device data hold time[8]	Troh	Tdrp – Tlbd – Tdicdr + 1.5	—	Tdicpr – Tdicdr – 1.5	ns
IP39	Write data setup time	Tds	Tdicdw – 1.5	Tdicdw	—	ns
IP40	Write data hold time	Tdh	Tdicpw – Tdicdw – 1.5	Tdicpw – Tdicdw	—	ns
IP41	Read period[2]	Tdicpr	Tdicpr – 1.5	Tdicpr	Tdicpr + 1.5	ns
IP42	Write period[3]	Tdicpw	Tdicpw – 1.5	Tdicpw	Tdicpw + 1.5	ns
IP43	Read down time[4]	Tdicdr	Tdicdr – 1.5	Tdicdr	Tdicdr + 1.5	ns
IP44	Read up time[5]	Tdicur	Tdicur – 1.5	Tdicur	Tdicur + 1.5	ns
IP45	Write down time[6]	Tdicdw	Tdicdw – 1.5	Tdicdw	Tdicdw + 1.5	ns
IP46	Write up time[7]	Tdicuw	Tdicuw – 1.5	Tdicuw	Tdicuw + 1.5	ns
IP47	Read time point[9]	Tdrp	Tdrp – 1.5	Tdrp	Tdrp + 1.5	ns

[1]The exact conditions have not been finalized, but will likely match the current customer requirement for their specific display. These conditions may be device-specific.

[2] Display interface clock period value for read:

$$Tdicpr = T_{HSP\_CLK} \cdot ceil\left[\frac{DISP\#\_IF\_CLK\_PER\_RD}{HSP\_CLK\_PERIOD}\right]$$

[3] Display interface clock period value for write:

$$Tdicpw = T_{HSP\_CLK} \cdot ceil\left[\frac{DISP\#\_IF\_CLK\_PER\_WR}{HSP\_CLK\_PERIOD}\right]$$

[4] Display interface clock down time for read:

$$Tdicdr = \frac{1}{2}T_{HSP\_CLK} \cdot ceil\left[\frac{2 \cdot DISP\#\_IF\_CLK\_DOWN\_RD}{HSP\_CLK\_PERIOD}\right]$$

[5] Display interface clock up time for read:

$$Tdicur = \frac{1}{2}T_{HSP\_CLK} \cdot ceil\left[\frac{2 \cdot DISP\#\_IF\_CLK\_UP\_RD}{HSP\_CLK\_PERIOD}\right]$$

[6] Display interface clock down time for write:

$$Tdicdw = \frac{1}{2}T_{HSP\_CLK} \cdot ceil\left[\frac{2 \cdot DISP\#\_IF\_CLK\_DOWN\_WR}{HSP\_CLK\_PERIOD}\right]$$

[7] Display interface clock up time for write:

$$Tdicuw = \frac{1}{2}T_{HSP\_CLK} \cdot ceil\left[\frac{2 \cdot DISP\#\_IF\_CLK\_UP\_WR}{HSP\_CLK\_PERIOD}\right]$$

[8] This parameter is a requirement to the display connected to the IPU

Table 59. Asynchronous Serial Interface Timing Parameters—Access Level (continued)

ID	Parameter	Symbol	Min.	Typ.[1]	Max.	Units
IP55	Controls hold time for read	Tdchr	Tdicpr – Tdicdr – 1.5	Tdicpr – Tdicdr	—	ns
IP56	Controls setup time for write	Tdcsw	Tdicuw – 1.5	Tdicuw	—	ns
IP57	Controls hold time for write	Tdchw	Tdicpw – Tdicdw – 1.5	Tdicpw – Tdicdw	—	ns
IP58	Slave device data delay[8]	Tracc	0	—	Tdrp[9] – Tlbd[10] – Tdicur – 1.5	ns
IP59	Slave device data hold time[8]	Troh	Tdrp – Tlbd – Tdicdr + 1.5	—	Tdicpr – Tdicdr – 1.5	ns
IP60	Write data setup time	Tds	Tdicdw – 1.5	Tdicdw	—	ns
IP61	Write data hold time	Tdh	Tdicpw – Tdicdw – 1.5	Tdicpw – Tdicdw	—	ns
IP62	Read period[2]	Tdicpr	Tdicpr – 1.5	Tdicpr	Tdicpr + 1.5	ns
IP63	Write period[3]	Tdicpw	Tdicpw – 1.5	Tdicpw	Tdicpw + 1.5	ns
IP64	Read down time[4]	Tdicdr	Tdicdr – 1.5	Tdicdr	Tdicdr + 1.5	ns
IP65	Read up time[5]	Tdicur	Tdicur – 1.5	Tdicur	Tdicur + 1.5	ns
IP66	Write down time[6]	Tdicdw	Tdicdw – 1.5	Tdicdw	Tdicdw + 1.5	ns
IP67	Write up time[7]	Tdicuw	Tdicuw – 1.5	Tdicuw	Tdicuw + 1.5	ns
IP68	Read time point[9]	Tdrp	Tdrp – 1.5	Tdrp	Tdrp + 1.5	ns

1 The exact conditions have not been finalized, but will likely match the current customer requirement for their specific display. These conditions may be device specific.

2 Display interface clock period value for read:

$$Tdicpr = T_{HSP\_CLK} \cdot ceil\left[\frac{DISP\#\_IF\_CLK\_PER\_RD}{HSP\_CLK\_PERIOD}\right]$$

3 Display interface clock period value for write:

$$Tdicpw = T_{HSP\_CLK} \cdot ceil\left[\frac{DISP\#\_IF\_CLK\_PER\_WR}{HSP\_CLK\_PERIOD}\right]$$

4 Display interface clock down time for read:

$$Tdicdr = \frac{1}{2}T_{HSP\_CLK} \cdot ceil\left[\frac{2 \cdot DISP\#\_IF\_CLK\_DOWN\_RD}{HSP\_CLK\_PERIOD}\right]$$

5 Display interface clock up time for read:

$$Tdicur = \frac{1}{2}T_{HSP\_CLK} \cdot ceil\left[\frac{2 \cdot DISP\#\_IF\_CLK\_UP\_RD}{HSP\_CLK\_PERIOD}\right]$$

6 Display interface clock down time for write:

$$Tdicdw = \frac{1}{2}T_{HSP\_CLK} \cdot ceil\left[\frac{2 \cdot DISP\#\_IF\_CLK\_DOWN\_WR}{HSP\_CLK\_PERIOD}\right]$$

7 Display interface clock up time for write:

$$Tdicuw = \frac{1}{2}T_{HSP\_CLK} \cdot ceil\left[\frac{2 \cdot DISP\#\_IF\_CLK\_UP\_WR}{HSP\_CLK\_PERIOD}\right]$$

8 This parameter is a requirement to the display connected to the IPU.

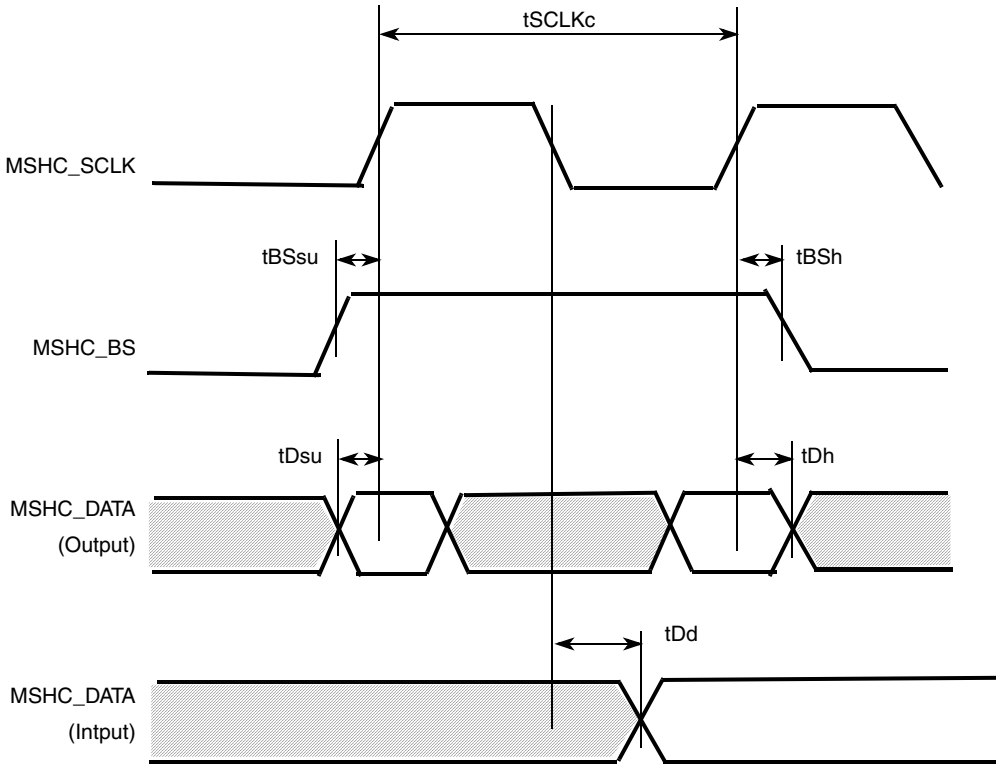


Figure 68. Transfer Operation Timing Diagram (Serial)

Figure 76 shows timing for PIO write, and Table 70 lists the timing parameters for PIO write.

Figure 76. PIO Write Timing Diagram

Table 70. PIO Write Timing Parameters

ATA Parameter	Parameter from Figure 76	Value	Controlling Variable
t1	t1	t1 (min.) = time_1 × T – (tskew1 + tskew2 + tskew5)	time_1
t2	t2w	t2 (min.) = time_2w × T – (tskew1 + tskew2 + tskew5)	time_2w
t9	t9	t9 (min.) = time_9 × T – (tskew1 + tskew2 + tskew6)	time_9
t3	—	t3 (min.) = (time_2w – time_on) × T – (tskew1 + tskew2 +tskew5)	If not met, increase time_2w
t4	t4	t4 (min.) = time_4 × T – tskew1	time_4
tA	tA	tA = (1.5 + time_ax) × T – (tco + tsui + tcable2 + tcable2 + 2*tbuf)	time_ax
t0	—	t0(min.) = (time_1 + time_2 + time_9) × T	time_1, time_2r, time_9
—	—	Avoid bus contention when switching buffer on by making ton long enough.	—
—	—	Avoid bus contention when switching buffer off by making toff long enough.	—

Table 81. SSI Receiver with External Clock Timing Parameters (continued)

ID	Parameter	Min.	Max.	Unit
SS25	(Tx/Rx) CK clock low period	36.0	—	ns
SS26	(Tx/Rx) CK clock fall time	—	6.0	ns
SS28	(Rx) CK high to FS (bl) high	–10.0	15.0	ns
SS30	(Rx) CK high to FS (bl) low	10.0	—	ns
SS32	(Rx) CK high to FS (wl) high	–10.0	15.0	ns
SS34	(Rx) CK high to FS (wl) low	10.0	—	ns
SS35	(Tx/Rx) External FS rise time	—	6.0	ns
SS36	(Tx/Rx) External FS fall time	—	6.0	ns
SS40	SRXD setup time before (Rx) CK low	10.0	—	ns
SS41	SRXD hold time after (Rx) CK low	2.0	—	ns

4.9.23 UART Electrical

This section describes the electrical information of the UART module.

4.9.23.1 UART RS-232 Serial Mode Timing

The following subsections give the UART transmit and receive timings in RS-232 serial mode.

4.9.23.1.11 UART Transmitter

Figure 96 depicts the transmit timing of UART in RS-232 serial mode, with 8 data bit/1 stop bit format. Table 82 lists the UART RS-232 serial mode transmit timing characteristics.

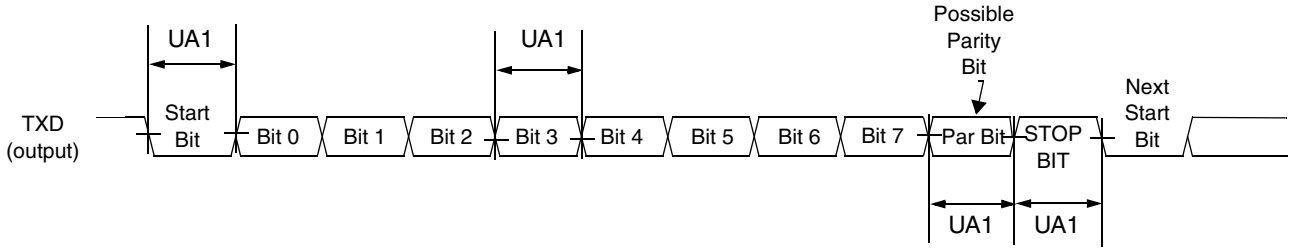


Figure 96. UART RS-232 Serial Mode Transmit Timing Diagram

Table 94. Silicon Revision 2.0 Signal Ball Map Locations (continued)

Signal ID	Ball Location
SD6	A17
SD7	B16
SD8	C14
SD9	A16
SDBA0	A6
SDBA1	B6
SDCKE0	D18
SDCKE1	E17
VDD	L7
VDD	N7
VDD	R7
VDD	F8
VDD	R8
VDD	F9
VDD	F12
VDD	R12
VDD	G13
VDD	H15
VDD	J15
VSS	A1
VSS	Y1
VSS	J8
VSS	M8
VSS	N8
VSS	J9

Signal ID	Ball Location
USBPHY1_VBUS	P18
USBPHY1_VDDA_BIAS	R20
USBPHY1_VSSA_BIAS	R18
USBPHY2_DM	Y17
USBPHY2_DP	Y18
VDD	M6
VDD	F7
VDD	J7
VSS	L9
VSS	N9
VSS	K10
VSS	P10
VSS	H11
VSS	H12
VSS	H13
VSS	J13
VSS	K13
VSS	L13
VSS	T17
VSS	A20
VSS	Y20
VSTBY	T9
WDOG_RST	Y12
XTAL_AUDIO	V19
XTAL24M	U20

[1] Not available for the MCIMX351.

Table 95. Silicon Revision 2.1 Signal Ball Map Locations

Signal ID	Ball Location
A0	A5
A1	D7
A10	F15
A11	D5
A12	F6
A13	B3
A14	D14
A15	D15
A16	D13
A18	D12
SDQS1	E11
A19	D11
A2	E7
A21	D10
SDQS2	E10
A22	D9
SDQS3	E9
A24	D8
A25	E8
A3	C6
A4	D6
A5	B5
A6	C5
A7	A4
A8	B4
A9	A3
ATA_BUFF_EN[1]	T5
ATA_CS0	V7
ATA_CS1	T7
ATA_DA0	R4
ATA_DA1	V1
ATA_DA2	R5
ATA_DATA0	Y5
ATA_DATA1	W5
ATA_DATA10	V3
ATA_DATA11	Y2
ATA_DATA12	U3
ATA_DATA13	W2
ATA_DATA14	W1
ATA_DATA15	T4
ATA_DATA2	V5
ATA_DATA3	U5
ATA_DATA4	Y4
ATA_DATA5	W4
ATA_DATA6	V4

Signal ID	Ball Location
ATA_DATA7	Y3
ATA_DATA8	U4
ATA_DATA9	W3
ATA_DIOR	Y6
ATA_DIOW	W6
ATA_DMACK	V6
ATA_DMARQ	T3
ATA_INTRQ	V2
ATA_IORDY	U6
ATA_RESET_B	T6
SDQS0	E14
BOOT_MODE0	W10
BOOT_MODE1	U9
CAPTURE	V12
RAS	E16
CLK_MODE0	Y10
CLK_MODE1	T10
CLKO	V10
COMPARE	T12
CONTRAST	L16
CS0	F17
CS1	E19
CS2	B20
CS3	C19
CS4	E18
CS5	F19
CSI_D10	V16
CSI_D11	T15
CSI_D12	W16
CSI_D13	V15
CSI_D14	U14
CSI_D15	Y16
CSI_D8	U15
CSI_D9	W17
CSI_HSYNC	V14
CSI_MCLK	W15
CSI_PIXCLK	Y15
CSI_VSYNC	T14
CSPI1_MISO	V9
CSPI1_MOSI	W9
CSPI1_SCLK	W8
CSPI1_SPI_RDY	T8
CSPI1_SS0	Y8
CSPI1_SS1	U8
CTS1	R3

Table 95. Silicon Revision 2.1 Signal Ball Map Locations (continued)

Signal ID	Ball Location
MA10	C4
MGND	N11
MLB_CLK	W13
MLB_DAT	Y13
MLB_SIG	W12
MVDD	P11
NF_CE0	G3
NFALE	F2
NFCLE	E1
NFRB	F3
NFRE_B	F1
NFWE_B	G2
NFWP_B	F4
NGND_ATA	M9
NGND_ATA	P9
NGND_ATA	L10
NGND_CRM	L11
NGND_CSI	N10
NGND_EMI1	H8
NVCC_EMI1	H10
NGND_EMI1	J10
NGND_EMI2	J11
NGND_EMI3	J12
NGND_EMI3	K12
NGND_JTAG	M13
NGND_LCDC	K11
NGND_LCDC	L12
NGND_MISC	M7
NGND_MISC	K8
NGND_MLB	M10
NGND_NFC	K9
NGND_SDIO	N12
NVCC_ATA	N6
NVCC_ATA	P6
NVCC_ATA	P7
NVCC_ATA	P8
NVCC_CRM	R9
NVCC_CSI	R11
NVCC_EMI1	G7
NVCC_EMI1	G8
NVCC_EMI1	G9
NVCC_EMI1	H9
NGND_EMI1	F10
NVCC_EMI1	G10
NVCC_EMI1	F11
NVCC_EMI1	G11

Signal ID	Ball Location
NVCC_EMI2	G12
NVCC_EMI2	F13
VSS	F14
NVCC_EMI3	G14
NVCC_JTAG	P16
NVCC_LCDC	H14
NVCC_LCDC	J14
NVCC_LCDC	L14
NVCC_LCDC	M14
NVCC_MISC	K6
NVCC_MISC	K7
NVCC_MISC	L8
NVCC_MLB	R10
NVCC_NFC	G6
NVCC_NFC	H6
NVCC_NFC	H7
NVCC_SDIO	P14
OE	E20
OSC_AUDIO_VDD	V20
OSC_AUDIO_VSS	U19
OSC24M_VDD	T19
OSC24M_VSS	T18
PGND	M12
PHY1_VDDA	M15
PHY1_VDDA	N20
PHY1_VSSA	N16
PHY1_VSSA	P20
PHY2_VDD	R13
PHY2_VSS	P12
POR_B	W11
POWER_FAIL	Y9
PVDD	N13
BCLK	E15
RESET_IN_B	U10
RTCK	U18
RTS1	U1
RTS2	G1
RW	C20
RXD1	U2
RXD2	H3
SCK4	L4
SCK5	L5
SCKR	K3
SCKT	J4
DQM1	C17
SD1	A19

Table 96. Silicon Revision 2.0 Ball Map—17 x 17, 0.8 mm Pitch[1] (continued)

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	
V	ATA_DA1	ATA_INTRQ	ATA_DATA10	ATA_DATA6	ATA_DATA2	ATA_DMACK	ATA_CS0	EXT_ARMCLK	CSPI1_MISO	CLKO	GPIO3_0	CAPTURE	SD2_DATA0	CSI_HSYNC	CSI_D13	CSI_D10	SD1_DATA3	SD1_CLK	XTAL_AUDIO	OSC_AUDIO_VDD	V
W	ATA_DATA14	ATA_DATA13	ATA_DATA9	ATA_DATA5	ATA_DATA1	ATA_DIOW	USBOTG_PWR	CSPI1_SCLK	CSPI1_MOSI	BOOT_MODE0	POR_B	MLB_SIG	MLB_CLK	SD2_CLK	CSI_MCLK	CSI_D12	CSI_D9	SD1_DATA2	DE_B	EXTAL_AUDIO	W
Y	VSS	ATA_DATA11	ATA_DATA7	ATA_DATA4	ATA_DATA0	ATA_DIOR	TEST_MODE	CSPI1_SS0	POWER_FAIL	CLK_MODE0	GPIO1_1	WDOG_RST	MLB_DAT	SD2_DATA2	CSI_PIXCLK	CSI_D15	USBPHY2_DM	USBPHY2_DP	SD1_CMD	VSS	Y

[1] See Table 95 for pins unavailable in the MCIMX351 SoC.

Table 97. Silicon Revision 2.1 Ball Map—17 x 17, 0.8 mm Pitch

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	
A	GND	D0	A9	A7	A0	SDBA0	SD30	SD27	SD24	SD23	SD21	SD18	SD15	SD14	SD10	SD9	SD6	SD4	SD1	GND	A
B	D5	D2	A13	A8	A5	SDBA1	SD31	SD28	SD26	SD22	SD20	SD19	SD12	SD13	SD11	SD7	SD0	SD2	DQM0	CS2	B
C	D8	D7	D4	MA10	A6	A3	A23	SD29	SD25	A20	SD17	SD16	A17	SD8	SD5	SD3	DQM1	DQM3	CS3	RW	C
D	D14	D10	D6	D1	A11	A4	A1	A24	A22	A21	A19	A18	A16	A14	A15	DQM2	SDCKE1	SDCKE0	ECB	LBA	D
E	NFCLE	D15	D12	D9	D3	D11	A2	A25	SDQS3	SDQS2	SDQS1	SDCLK	SDCLK_B	SDQS0	BCLK	RAS	CAS	CS4	CS1	OE	E
F	NFRE_B	NFALE	NFRB	NFWP_B	D13	A12	VDD7	VDD7	VDD7	GND	NVCC_EMI1	VDD7	NVCC_EMI2	GND	A10	EB1	CS0	EB0	CS5	LD0	F
G	RTS2	NFWE_B	NF_CE0	TX0	CTS2	NVCC_NFC	NVCC_EMI1	NVCC_EMI1	NVCC_EMI1	NVCC_EMI1	NVCC_EMI1	NVCC_EMI2	VDD6	NVCC_EMI3	SDWE	LD3	LD2	LD1	LD4	LD7	G
H	TX1	TXD2	RXD2	TX4_RX1	TX2_RX3	NVCC_NFC	NVCC_NFC	GND	NVCC_EMI1	NVCC_EMI1	GND	GND	NVCC_EMI2	NVCC_LCDC	VDD5	LD5	LD8	LD6	LD9	LD10	H
J	FST	TX3_RX2	TX5_RX0	SCKT	HCKT	STXFS5	VDD1	GND	GND	GND	GND	GND	GND	NVCC_LCDC	VDD5	LD12	LD14	LD11	LD13	LD15	J
K	STXD5	HCKR	SCKR	SRXD5	FSR	NVCC_MISC	NVCC_MISC	GND	GND	GND	GND	GND	GND	LD16	LD22	LD20	LD21	LD18	LD17	LD19	K
L	SRXD4	STXFS4	I2C2_CLK	SCK4	SCK5	FEC_TDATA3	VDD2	NVCC_MISC	GND	GND	GND	GND	GND	NVCC_LCDC	D3_FPSHIFT	CONTRAST	D3_CLS	D3_HSYNC	LD23	D3_DRDY	L
M	I2C2_DAT	STXD4	FEC_RDATA2	FEC_TDATA1	FEC_TDATA2	VDD2	GND	GND	GND	GND	FUSE_VSS	PGND	GND	NVCC_LCDC	PHY1_VDDA	TTM_PAD	D3_REV	D3_SPL	D3_VSYNC	I2C1_CLK	M
N	FEC_RDATA3	FEC_RDATA1	FEC_RX_ERR	FEC_TX_ERR	FEC_CRS	NVCC_ATA	VDD3	GND	GND	GND	MGND	GND	PVDD	USBPHY1_UPLLGND	USBPHY1_UPLLVDD	PHY1_VSSA	I2C1_DAT	USBPHY1_UID	USBPHY1_DM	PHY1_VDDA	N

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